

INFORMATION DISCLOSURE
STATEMENT BY APPLICANT
Form PTO-1449 (Modified)
(Use several sheets if necessary)

COMPLETE IF KNOWN

Application Number	10/642,370				
Confirmation Number	2543				
Filing Date	08/15/2003				
First Named Inventor	Man Wang				
Group Art Unit	2819				
Examiner Name					
Sheet	1	of	4	Attorney Docket No.	384848008US

U.S. PATENT DOCUMENTS

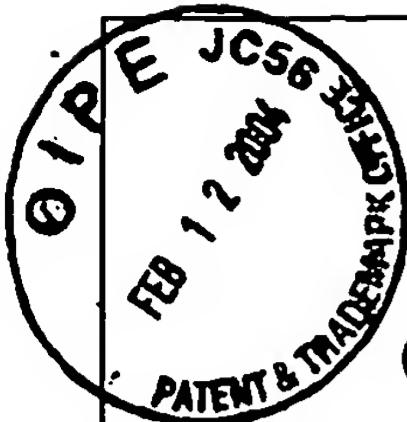
Examiner Initials*	Cite No.	U.S. Patent or Application		Name of Patentee or Inventor of Cited Document	Date of Publication or Filing Date of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		NUMBER	Kind Code (if known)			
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1		4,322,822		McPherson	03/30/82	
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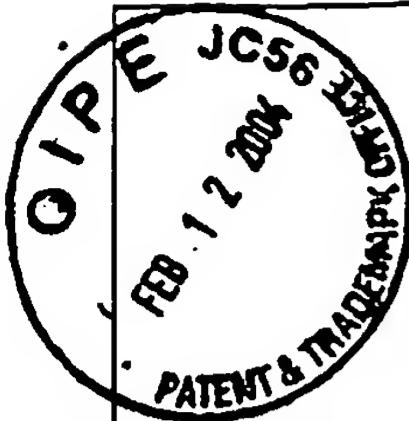
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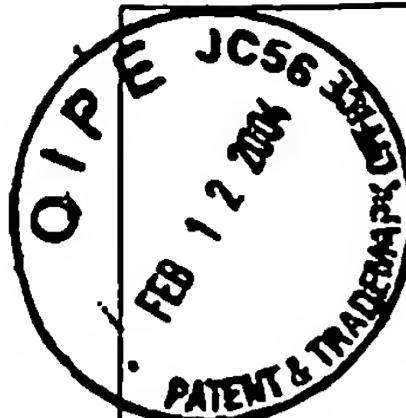
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		Office	NUMBER			
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OTHER PRIOR ART-NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume/issue number(s), publisher, city and/or country where published.			
JK	*	MIRANDA, ENRIQUE et al; Analytic Modeling of Leakage Current Through Multiple Breakdown Paths in SiO ₂ Films; 39 th Annual International Reliability Physics Symposium; Orlando, FL 2001, pp.367-379			

EXAMINER	<i>Dal D. Clay</i>	DATE CONSIDERED	<i>2/1/05</i>
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Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume/issue number(s), publisher, city and/or country where published.	T
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<i>Eric D. Clay</i>	2/1/05
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